imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





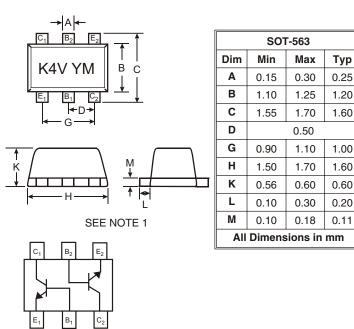
NPN DUAL SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Die Construction
- Complementary PNP Type Available (BC857BV)
- Ultra-Small Surface Mount Package
- Lead Free Plating

Mechanical Data

- Case: SOT-563, Molded Plastic
- Case material UL Flammability Rating Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin (Note 2) Solderable per MIL-STD-202, Method 208
- Marking (See Page 2): K4V
- Ordering & Date Code Information: See Page 2
- Weight: 0.002 grams (approx.)



Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	50	V	
Collector-Emitter Voltage	V _{CEO}	45	V	
Emitter-Base Voltage	V _{EBO}	6.0	V	
Collector Current	Ic	100	mA	
Power Dissipation (Note 3)	Pd	150	mW	
Thermal Resistance, Junction to Ambient (Note 3)	R _{θJA}	833	°C/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C	

Notes:

1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

2. If lead-bearing terminal plating is required, please contact your Diodes Inc. sales representative for availability and minimum order details.

3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	n Typ Max Unit		Test Condition		
Collector-Base Breakdown Voltage	(Note 4)	V _{(BR)CBO}	50	- JP	_	V	$I_{\rm C} = 10 \mu A, I_{\rm B} = 0$
Collector-Emitter Breakdown Voltage	(Note 4)	V _{(BR)CEO}	45			V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	(Note 4)	V _{(BR)EBO}	6	_	_	V	$I_{E} = 1 \mu A, I_{C} = 0$
DC Current Gain	(Note 4)	h _{FE}	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	(Note 4)	V _{CE(SAT)}	—	_	100 300	mV	$I_{C} = 10mA, I_{B} = 0.5mA$ $I_{C} = 100mA, I_{B} = 5.0mA$
Base-Emitter Saturation Voltage	(Note 4)	V _{BE(SAT)}		700 900	_	mV	$I_{C} = 10$ mA, $I_{B} = 0.5$ mA $I_{C} = 100$ mA, $I_{B} = 5.0$ mA
Base-Emitter Voltage	(Note 4)	V _{BE}	580	660	700 770	mV	$V_{CE} = 5.0V, I_C = 2.0mA$ $V_{CE} = 5.0V, I_C = 10mA$
Collector-Emitter Cutoff Current	(Note 4)	I _{CBO} I _{CBO}		_	15 5.0	nA μA	$V_{CB} = 30V$ $V_{CB} = 30V$, $T_A = 150^{\circ}C$
Gain Bandwidth Product		f⊤	100	_	_	MHz	$V_{CE} = 5.0V, I_C = 10mA,$ f = 100MHz
Output Capacitance		Сово		_	4.5	pF	V _{CB} = 10V, f = 1.0MHz
Noise Figure		NF	_	_	10	dB	$V_{CE} = 5V, R_S = 2.0k\Omega, f = 1.0kHz, BW = 200Hz$

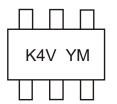
Ordering Information (Note 5)

Device	Packaging	Shipping		
BC847BV-7	SOT-563	3000/Tape & Reel		

Notes:

Short duration pulse test used to minimize self-heating effect.
For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K4V = Product Type Marking Code YM = Date Code Marking Y = Year (ex: P = 2003) M = Month (ex: 9 = September)

Date Code Key

Year	2003	3	2004	2005	2	006	20	07	200	8	200	9
Code	Р		R	S T		ι	U		V		W	
Month	Jan	Feb	March	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

